

The listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1. (Currently Amended) A semiconductor device comprising:  
a support which is ~~a sheet comprising a ferromagnetic material~~ including a magnetic sheet;  
~~a binding an adhesive material adjacent to the sheet comprising the ferromagnetic material~~ the support including the magnetic sheet; ~~[[and]]~~  
~~an element on~~ an insulating film adjacent to the binding adhesive material[[,]]; and  
a thin film transistor adjacent to the insulating film.
2. (Currently Amended) A semiconductor device according to claim 1, wherein the element is ~~a thin film transistor, a light emitting element having a layer containing an organic compound,~~ the semiconductor device further comprises an element selected from group consisting of an element having liquid crystal, a memory element, a thin film diode, a photoelectric transducer comprising PIN junctions of silicon, or a silicon resistance element.
3. (Currently Amended) A semiconductor device according to claim 1 or claim 2, wherein the magnetic sheet ~~comprising the ferromagnetic material~~ is formed by mixing soft magnetic powder and synthetic resin, ~~then~~ and by magnetizing said mixture.
4. (Currently Amended) A semiconductor device comprising:  
a support which is ~~a binding~~ an adhesive material;  
a protective film ~~[[on]]~~ over the binding material support;

an insulating film over the protective film; and

a middle processing component comprising a control section and an operation section, and a memory unit ~~[[on an]]~~ over the insulating film, ~~adjacent to the binding material; and~~

wherein the middle processing component includes a thin film transistor of n-channel type and a thin film transistor of p-channel type.

5. (Previously Presented) A semiconductor device according to any one of claims 1, 2, or 4, wherein the semiconductor device is an authentication card, a video camera, a digital camera, a goggle type display, a car navigation system, a personal computer, or a mobile information terminal.

6.-16. (Canceled)

17. (New) A semiconductor device comprising:

a support including a magnetic sheet;

an adhesive material adjacent to the support including a magnetic sheet;

an insulating film adjacent to the adhesive material; and

a light emitting element adjacent to the insulating film,

wherein the light emitting element comprises a first electrode, a second electrode, and a light emitting layer.

18. (New) A semiconductor device comprising:

a support including a magnetic sheet;

an adhesive material over the support including a magnetic sheet;

an insulating film over the adhesive material;

a thin film transistor over the insulating film; and

a light emitting element over the insulating film,

wherein the light emitting element comprises a first electrode, a second electrode, and a light emitting layer, and  
wherein the first electrode is electrically connected to the thin film transistor.

19. (New) A semiconductor device comprising:  
an insulating film;  
a thin film transistor over the insulating film;  
a light emitting element over the insulating film;  
an adhesive material over the light emitting element; and  
a support including a magnetic sheet over the adhesive material,  
wherein the light emitting element comprises a first electrode, a second electrode, and a light emitting layer, and  
wherein the first electrode is electrically connected to the thin film transistor.

20. (New) A semiconductor device comprising:  
a first protective film;  
a thin film transistor over the first protective film;  
a support which is an adhesive material over the thin film transistor; and  
a second protective film over the support.

21. (New) An article comprising:  
a first support including magnetic material;  
a second support including a magnetic sheet adjacent to the first support;  
an adhesive material adjacent to the first support including a magnetic sheet;  
an insulating film adjacent to the adhesive material; and  
a thin film transistor adjacent to the insulating film.

22. (New) An article according to claim 21, wherein the first support is a steel plate.

23. (New) A semiconductor device according to claim 1, wherein the magnetic sheet comprises a material selected from the group consisting of barium ferrite, strontium ferrite, and rare earth magnet.

24. (New) A semiconductor device according to claim 17, wherein the magnetic sheet comprises a material selected from the group consisting of barium ferrite, strontium ferrite, and rare earth magnet.

25. (New) A semiconductor device according to claim 18, wherein the magnetic sheet comprises a material selected from the group consisting of barium ferrite, strontium ferrite, and rare earth magnet.

26. (New) A semiconductor device according to claim 19, wherein the magnetic sheet comprises a material selected from the group consisting of barium ferrite, strontium ferrite, and rare earth magnet.

27. (New) An article according to claim 21, wherein the magnetic sheet comprises a material selected from the group consisting of barium ferrite, strontium ferrite, and rare earth magnet.